



#### 60V N-CHANNEL SELF-PROTECTED ENHANCEMENT MODE LOW-SIDE IntelliFET

#### **Product Summary**

Continuous Drain Source Voltage: 60V

• On-State Resistance: 200mΩ

Nominal Load Current (V<sub>IN</sub> = 5V): 2.0A

Clamping Energy: 120mJ

#### **Description**

The ZXMS6005N8Q is a self-protected low-side IntelliFET<sup>TM</sup> MOSFET with logic level input. It integrates overtemperature, overcurrent, overvoltage (active clamp) and ESD protected logic level functionality. The ZXMS6005N8Q is ideal as a general purpose switch driven from 3.3V or 5V microcontrollers in harsh environments where standard MOSFETs are not rugged enough.

#### **Applications**

- Especially Suited for Loads with a High In-rush Current Such as Lamps and Motors
- All Types of Resistive, Inductive and Capacitive Loads in Switching Applications
- µC Compatible Power Switch for 12V and 24V DC Applications
- · Replaces Electromechanical Relays and Discrete Circuits
- Linear Mode Capability the current-limiting protection circuitry
  is designed to deactivate at low V<sub>DS</sub> to minimize on-state power
  dissipation. The maximum DC operating current is therefore
  determined by the thermal capability of the package/board
  combination, rather than by the protection circuitry. This does not
  compromise the product's ability to self-protect at low V<sub>DS</sub>

#### **Features and Benefits**

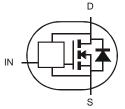
- Low Input Current
- Logic Level Input (3.3V and 5V)
- Short Circuit Protection with Auto Restart
- Overvoltage Protection (Active Clamp)
- Thermal Shutdown with Auto Restart
- Overcurrent Protection
- Input Protection (ESD)
- High Continuous Current Rating
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

#### **Mechanical Data**

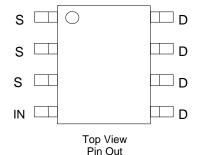
- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish @3
- Weight: 80.2mg (Approximate)



Top View



Device Symbol



#### Ordering Information (Note 5)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXMS6005N8Q-13	6005N8	13	12	2,500 units

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product\_compliance\_definitions.html.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

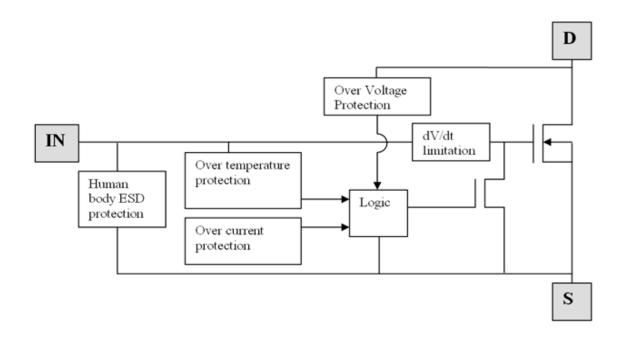
# Marking Information



Oll = Manufacturer's Marking 6005N8 = Product Type Marking Code YYWW = Date Code Marking YY: Year WW: Week: 01~52; 52 represents 52 and 53 week



### **Functional Block Diagram**



## Absolute Maximum Ratings (@T<sub>A</sub>= +25°C, unless otherwise stated.)

Characteristic	Symbol	Value	Unit
Continuous Drain-Source Voltage	V <sub>DS</sub>	60	V
Drain-Source Voltage for Short Circuit Protection	V <sub>DS(SC)</sub>	24	V
Continuous Input Voltage	V <sub>IN</sub>	-0.5 to +6	V
Continuous Input Current @-0.2V $\leq$ V <sub>IN</sub> $\leq$ 6V Continuous Input Current @V <sub>IN</sub> $<$ -0.2V or V <sub>IN</sub> $>$ 6V	I <sub>IN</sub>	No Limit   I <sub>IN</sub>   ≤ 2	mA
Pulsed Drain Current @V <sub>IN</sub> = 3.3V	I <sub>DM</sub>	5	А
Pulsed Drain Current @V <sub>IN</sub> = 5V	I <sub>DM</sub>	6	Α
Continuous Source Current (Body Diode) (Note 6)	Is	2.5	Α
Pulsed Source Current (Body Diode)	I <sub>SM</sub>	10	Α
Unclamped Single Pulse Inductive Energy, T <sub>J</sub> = +25°C, I <sub>D</sub> = 0.5A, V <sub>DD</sub> = 24V	E <sub>AS</sub>	120	mJ
Electrostatic Discharge (Human Body Model)	V <sub>HBM</sub>	4,000	V
Charged Device Model	V <sub>CDM</sub>	1,000	V

### **Recommended Operating Conditions**

The ZXMS6005N8Q is optimized to use with  $\mu C$  operating from 3.3V and 5V supplies.

Characteristic	Symbol	Min	Max	Unit
Input Voltage Range	V <sub>IN</sub>	0	5.5	V
Ambient Temperature Range	T <sub>A</sub>	-40	+125	°C
High Level Input Voltage for MOSFET to be On	VIH	3	5.5	V
Low Level Input Voltage for MOSFET to be Off	V <sub>IL</sub>	0	0.7	V
Peripheral Supply Voltage (Voltage to Which Load is Referred)	V <sub>P</sub>	0	24	V

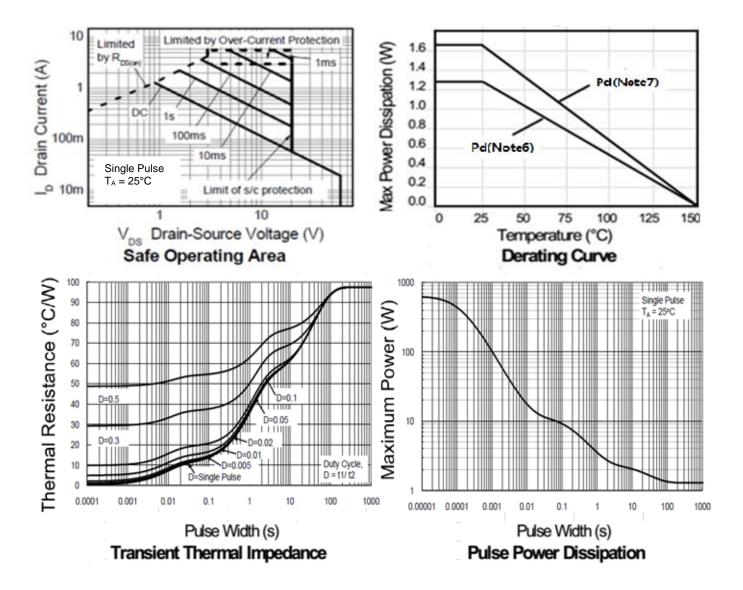


## Thermal Resistance (@T<sub>A</sub>= +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation at T <sub>A</sub> = +25°C (Note 6) Linear Derating Factor	P <sub>D</sub>	1.28 10	W mW/°C
Power Dissipation at T <sub>A</sub> = +25°C (Note 7) Linear Derating Factor	P <sub>D</sub>	1.65 12.4	W mW/°C
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>0JA</sub>	98	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	R <sub>0JA</sub>	76	°C/W
Thermal Resistance, Junction to Case (Note 8)	ReJC	12	°C/W
Operating Temperature Range	TJ	-40 to +150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

Notes:

- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
- 7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.
- 8. Thermal resistance between junction and the mounting surfaces of drain and source pins.





### Electrical Characteristics (@T<sub>A</sub>= +25°C, unless otherwise stated.)

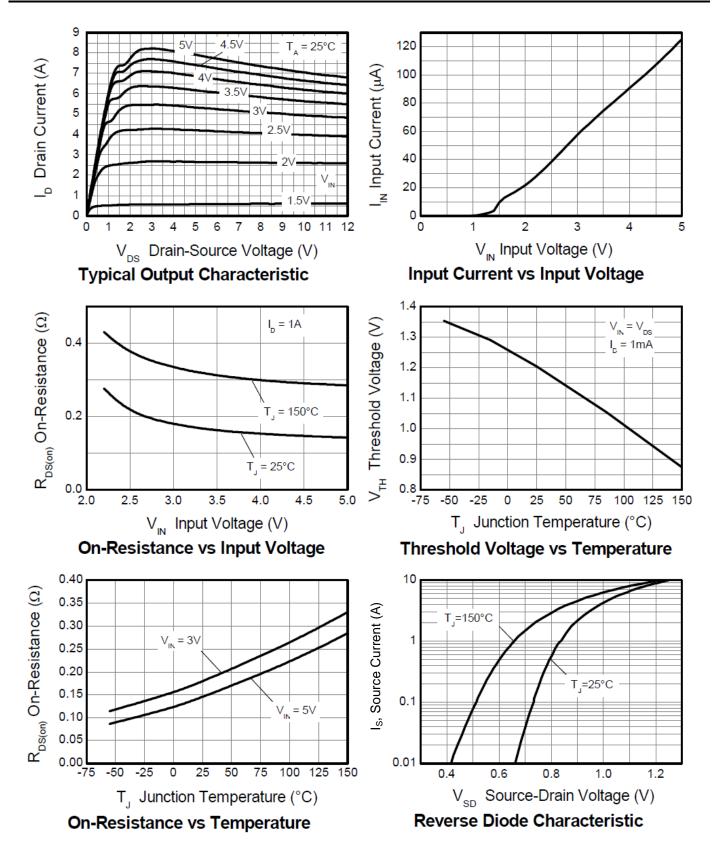
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Static Characteristics						
Drain-Source Clamp Voltage	V <sub>DS(AZ)</sub>	60	65	70	V	$I_D = 10 \text{mA}$
Off-State Drain Current		_	_	1		$V_{DS} = 12V, V_{IN} = 0V$
Oil-State Drain Current	I <sub>DSS</sub>		_	2	μΑ	$V_{DS} = 36V, V_{IN} = 0V$
Input Threshold Voltage	V <sub>IN(TH)</sub>	0.7	1	1.5	V	$V_{DS} = V_{GS}$ , $I_D = 1mA$
Innut Current			60	100		V <sub>IN</sub> = 3V
Input Current	I <sub>IN</sub>	_	120	200	μA	$V_{IN} = 5V$
Input Current While Overtemperature Active	_	_	_	300	μΑ	V <sub>IN</sub> = 5V
Static Drain-Source On-State Resistance	7	_	170	250	mΩ	$V_{IN} = 3V, I_D = 1.0A$
Static Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	_	150	200	mu	$V_{IN} = 5V, I_D = 1.0A$
Continuous Prais Current (Note 6)	- I <sub>D</sub>	1.4	_			V <sub>IN</sub> = 3V, T <sub>A</sub> = +25°C
Continuous Drain Current (Note 6)		1.6	_		A	$V_{IN} = 5V, T_A = +25^{\circ}C$
Continuous Drain Current (Note 7)		1.9	_			$V_{IN} = 3V, T_A = +25^{\circ}C$
Continuous Drain Current (Note 7)		2.0	_	_		$V_{IN} = 5V, T_A = +25^{\circ}C$
Current Limit (Note 9)	I <sub>D(LIM)</sub>	2.2	5	_	Α	$V_{IN} = 3V$
Current Limit (Note 9)		3.3	7	_	A	$V_{IN} = 5V$
Dynamic Characteristics						
Turn-On Delay Time	t <sub>D(ON)</sub>	_	5	_		
Rise Time	t <sub>R</sub>	_	14	_	0	10)/ 1 0 5 1 1/ 5 1/
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	34		μs	$V_{DD} = 12V$ , $I_D = 0.5A$ , $V_{GS} = 5V$
Fall Time	t <sub>F</sub>	_	19	_		
Overtemperature Protection						
Thermal Overload Trip Temperature (Note 10)	$T_{JT}$	+150	+175	_	°C	_
Thermal Hysteresis (Note 10)	$\Delta T_{JT}$	_	+10		°C	_

Notes:

The drain current is restricted only when the device is in saturation (see graph "Typical Output Characteristic"). This allows the device to be used in the fully on state without interference from the current limit. The device is fully protected at all drain currents, as the low power dissipation generated outside saturation makes current limit unnecessary.
 Overtemperature protection is designed to prevent device destruction under fault conditions. Fault conditions are considered as "outside" normal operating range, so this part is not designed to withstand over-temperature for extended periods.

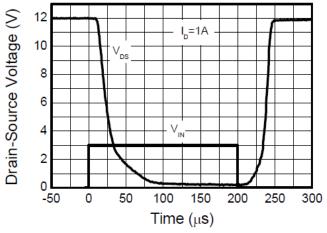


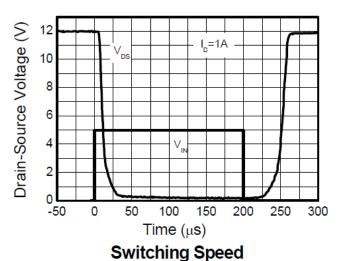
# **Typical Characteristics**



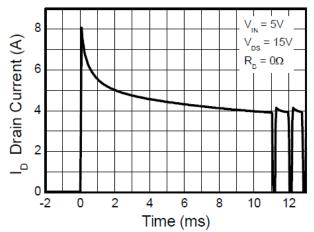


## **Typical Characteristics** (Cont.)





**Switching Speed** 



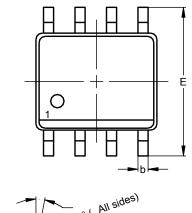
**Typical Short Circuit Protection** 

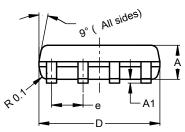


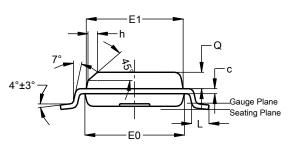
### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8





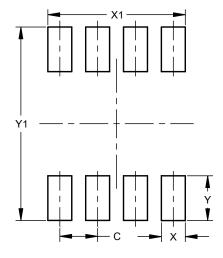


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Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
q	0.30	0.50	0.40		
C	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
Ф			1.27		
h	-		0.35		
Г	0.62	0.82	0.72		
Ø	0.60	0.70	0.65		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8



Dimensions	Value (in mm)		
С	1.27		
Х	0.802		
X1	4.612		
Y	1.505		
Y1	6.50		



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